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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No. : 10/727,595
Applicant : Gerhard Enders
Filed : December 5, 2003
TC/A.U. : 2811
Examiner : OWENS, Douglas W.
Confirmation No. : 7500
Docket No. : 0928.0006C
Customer No. : 27896
Title : Integrated Semiconductor Memory with a Selection
Transistor Formed at a Ridge (as amended)

Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450

TRANSMITTAL LETTER

Enclosed are the following documents in response to the Office Action mailed December 1, 2004, for the above-identified application:

- ☒ Second Supplemental Amendment (4 Pages)
- ☐ Petition for Extension of Time
- ☐ Request for Approval of Drawing Changes
- ☐ Notice of Appeal
- ☐ Associate Power
- ☐ Revocation and New Power
- ☐ Change of Address
- ☐ Return receipt postcard
- ☐ Check No. _____ in the amount of \$ _____ for the total fee as calculated below
- ☐ Other:

The fee has been calculated as follows:

	NO OF CLAIMS REMAINING	NO. OF CLAIMS PREVIOUSLY PAID FOR	NO OF EXCESS CLAIMS	RATE	FEE
Total Claims	18	- 20 =	0	\$50.00	0.00
Independent Claims	1	- 3 =	0	\$200.00	0.00
If multiple dependent claims are presented, add \$360.00					0.00
Total Amendment Fee					0.00
<input type="checkbox"/> Applicant claims Small Entity Status (subtract 50% of Total Application Fee)					0.00
Other fees: (specify)					0.00
TOTAL FEE DUE					0.00


- ☐ A check for the total fee is attached.
- ☐ Please charge \$ to Deposit Account No. 05-0460 for the total fee. This paper is being submitted in duplicate.
- ☒ The Commissioner is hereby authorized to charge any additional appropriate fees under 37 C.F.R. §§1.16, 1.17, and 1.21 that may be required by this paper, and to credit any overpayment, to Deposit Account No. 05-0460.

Dated: 6/10/05

EDELL, SHAPIRO & FINNAN, LLC
CUSTOMER NO. 27896
1901 Research Boulevard, Suite 400
Rockville, MD 20850
(301) 424-3640

By:

Respectfully submitted by
EDELL, SHAPIRO & FINNAN, LLC


Heather Morin
Reg. No. 37,336



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SECOND SUPPLEMENTAL AMENDMENT

Sir:

Further in response to the Office Action mailed December 1, 2004, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Abstract begin on page 3 of this paper.

Remarks begin on page 4 of this paper.